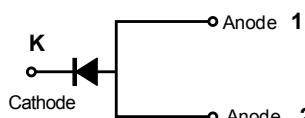


DST1545S



Pin out



Description

Littelfuse DST series Ultra Low V_F Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industry applications by providing high temperature, low leakage and lower V_F products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

Features

- Ultra low forward voltage drop
- Single die in TO-277B Package
- High frequency operation
- MSL: Level 1 - unlimited
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)
- High junction temperature capability
- Trench MOS Schottky technology

Applications

- Switching mode power supply
- Free-Wheeling diodes
- DC/DC converters
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V_{RWM}	-	45	V
Average Forward Current	$I_{F(AV)}$	50% duty cycle @ $T_L = 125^\circ\text{C}$ rectangular wave form	15	A
Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 ms, half Sine pulse	200	A

Electrical Characteristics

Parameters	Symbol	Test Conditions	Typ	Max	Unit
Forward Voltage Drop*	V_{F1}	@5A, Pulse, $T_j = 25^\circ\text{C}$	0.38	0.50	V
		@7.5A, Pulse, $T_j = 25^\circ\text{C}$	0.40	0.52	
		@15A, Pulse, $T_j = 25^\circ\text{C}$	0.46	0.58	
	V_{F2}	@5A, Pulse, $T_j = 125^\circ\text{C}$	0.25	0.39	
		@7.5A, Pulse, $T_j = 125^\circ\text{C}$	0.28	0.42	
		@15A, Pulse, $T_j = 125^\circ\text{C}$	0.37	0.51	
Reverse Current*	I_{R1}	@ V_R = rated V_R , $T_j = 25^\circ\text{C}$	0.21	1.5	mA
	I_{R2}	@ V_R = rated V_R , $T_j = 125^\circ\text{C}$	150	150	
Junction Capacitance	C_T	@ $V_R = 5\text{V}$, $T_C = 25^\circ\text{C}$, $f_{SIG} = 1\text{MHz}$	868	-	pF

* Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications

Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	T_J	DC operation	-55 to +150	°C
Storage Temperature	T_{stg}		-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	R_{thJA}		75	°C/W
Maximum Thermal Resistance Junction to Lead	R_{thJL}		3.5	°C/W
Approximate Weight	wt		0.08	g
Case Style			TO-277B	

Figure 1: Typical Junction Capacitance

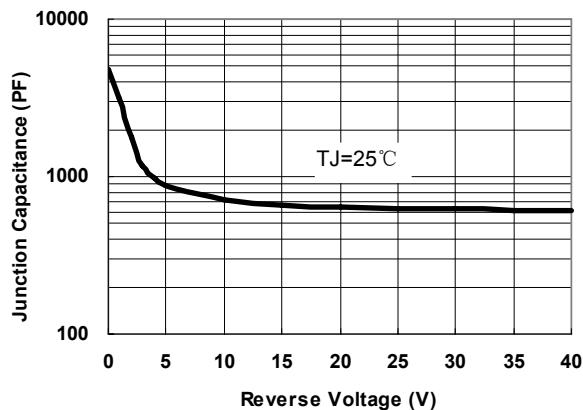


Figure 2: Typical Reverse Characteristics

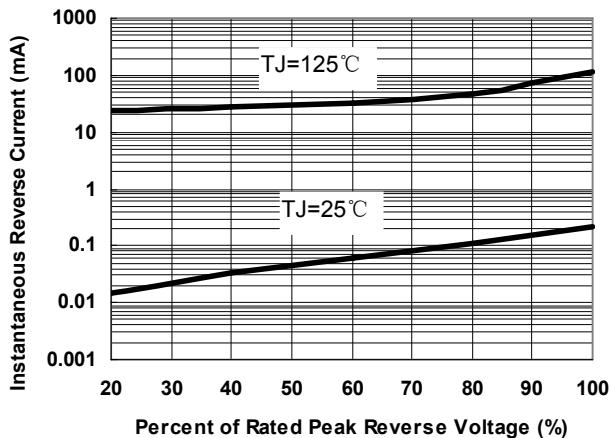
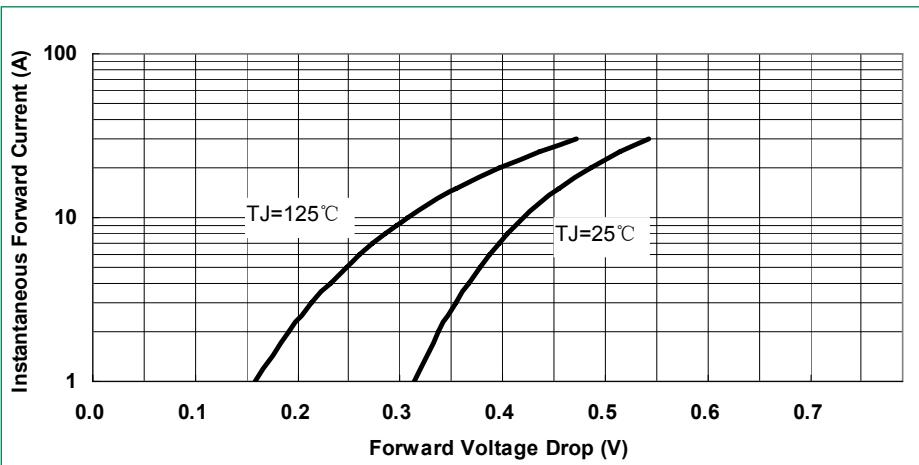
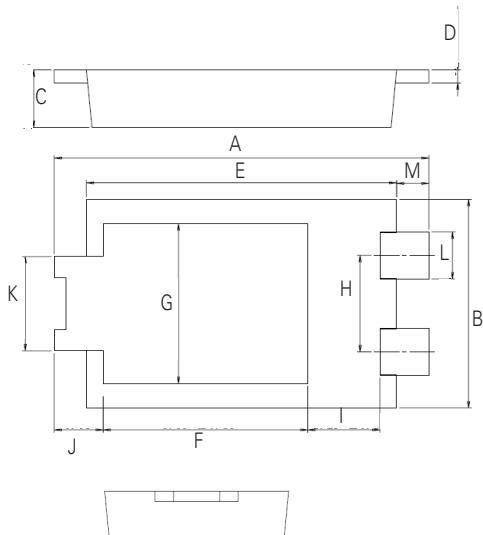


Figure 3: Typical Instantaneous Forward Voltage Characteristics



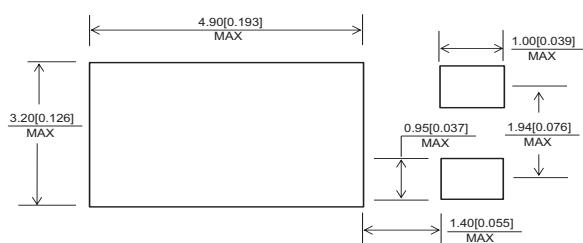
Dimensions-TO-277B



Symbol	Millimeters		
	Min	Typ	Max
A	6.30	6.50	6.70
B	3.88	3.98	4.08
C	0.95	1.10	1.25
D	0.20	0.25	0.30
E	5.28	5.38	5.48
F	3.40	3.55	3.70
G	2.90	3.05	3.20
H	1.74	1.84	1.94
I	1.10	1.25	1.40
J	-	0.85	-
K	1.70	1.80	1.90
L	0.85	0.90	0.95
M	-	0.56	-

Part Numbering and Marking System

Mounting Pad Layout

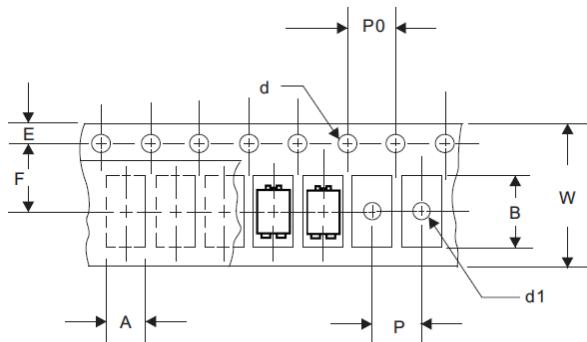


DST = Device Type
 15 = Forward Current (15A)
 45 = Reverse Voltage (45V)
 S = Package Type
 LF = Littelfuse
 YY = Year
 WW = Week
 L = Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
DST1545S	DST1545S	5000pcs / Reel	5000

Carrier Tape & Reel Specification



Symbol	Millimeters	
	Min	Max
A	4.28	4.48
B	6.80	7.00
d	1.40	1.60
d1	-	1.50
E	1.65	1.85
F	5.40	5.60
P	7.90	8.10
P0	3.90	4.10
W	11.70	12.30